RoHS

COMPLIANT



### Vishay General Semiconductor

## **Dual Common Cathode High Voltage Schottky Rectifier**



1 2 3
PIN 1 O PIN 2
PIN 3 O CASE

PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	2 x 30 A			
$V_{RRM}$	100 V			
I <sub>FSM</sub>	350 A			
V <sub>F</sub> at I <sub>F</sub> = 30 A	0.64 V			
T <sub>J</sub> max.	175 °C			
Package	TO-220AB			
Diode variations	Common cathode			

#### **FEATURES**

Power pack



- Low power losses, high efficiency
- Low forward voltage drop
- · High forward surge capability
- · High frequency operation
- Solder dip 260 °C, 40 s
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

#### TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, or polarity protection application.

#### **MECHANICAL DATA**

Case: TO-220AB

Epoxy meets UL 94 V-0 flammability rating

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A

whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

PARAMETER	SYMBOL	MBR60100CT	UNIT	
Maximum repetitive peak reverse voltage		$V_{RRM}$	100	V
Working peak reverse voltage		$V_{RWM}$	100	V
Maximum DC blocking voltage		$V_{DC}$	100	V
Maximum average forward rectified current	total device	ı	60	А
	per diode	I <sub>F(AV)</sub>	30	
Peak forward surge current 8.3 ms single half sine-wave superir on rated load per diode	mposed	I <sub>FSM</sub>	350	Α
Peak repetitive reverse current per diode at $t_p$ = 2 $\mu$ s, 1 kHz	I <sub>RRM</sub>	1.0	Α	
Peak non-repetitive reverse surge energy per diode (8/20 µs wa	E <sub>RSM</sub>	25	mJ	
Non-repetitive avalanche energy per diode at 25 °C, I <sub>AS</sub> = 1.0 A, L = 40 mH		E <sub>AS</sub>	20	mJ
Voltage rate of change (rated V <sub>R</sub> )	dV/dt	10 000	V/µs	
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	-65 to +175	°C	



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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>C</sub> = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode (1)	I <sub>F</sub> = 30 A	T <sub>J</sub> = 25 °C	- V <sub>F</sub>	0.78	0.82	- V	
	I <sub>F</sub> = 60 A			0.92	1		
	I <sub>F</sub> = 30 A	T <sub>J</sub> = 125 °C		0.64	0.69		
	I <sub>F</sub> = 60 A			0.78	0.83		
Reverse current per diode (2)	V 100 V	T <sub>J</sub> = 25 °C	I <sub>R</sub>	8	100	μA	
	V <sub>R</sub> = 100 V	T <sub>J</sub> = 125 °C		8.5	20	mA	

#### **Notes**

<sup>(2)</sup> Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T <sub>C</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	MBR60100CT	UNIT		
Typical thermal resistance per diode	$R_{ heta JC}$	0.5	°C/W		

ORDERING INFORMATION (Example)								
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
TO-220AB	MBR60100CT-E3/45	2.068	45	50/tube	Tube			

### **RATINGS AND CHARACTERISTICS CURVES** ( $T_C = 25$ °C unless otherwise noted)

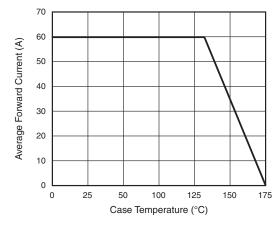


Fig. 1 - Forward Derating Curve

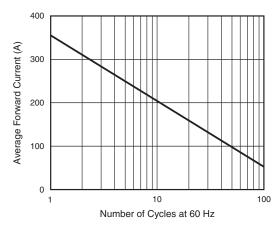


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

<sup>(1)</sup> Pulse test: 300µs pulse width, 1 % duty cycle

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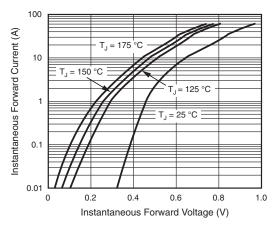


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

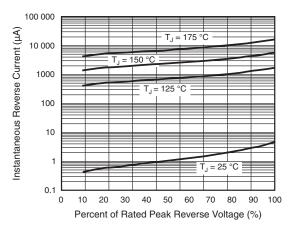


Fig. 4 - Typical Reverse Characteristics Per Diode

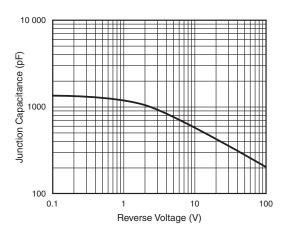


Fig. 5 - Typical Junction Capacitance Per Diode

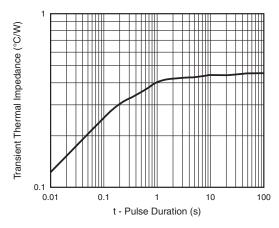
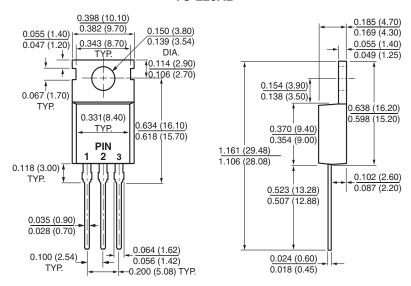


Fig. 6 - Typical Transient Thermal Impedance Per Diode

### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

#### TO-220AB



Revision: 17-Aug-15 3 Document Number: 88892

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